



# TGA2524-SM

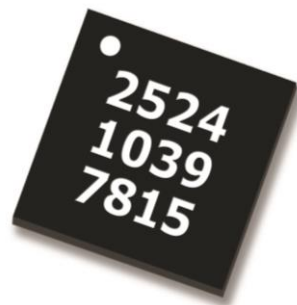
## Ku Band GaAs Driver Amplifier

### General Description

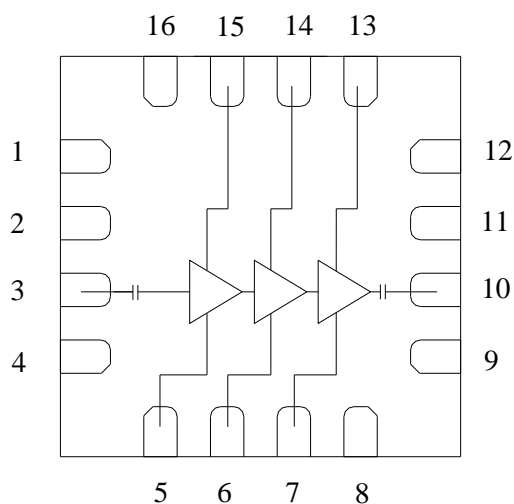
The Qorvo TGA2524-SM is a Ku-Band GaAs Power Amplifier. The TGA2524-SM operates from 11.3 – 16 GHz and is designed using Qorvo's power pHEMT production process.

TGA2524-SM has a typical gain of 23dB, and can deliver 26.5 dBm of saturated output power and 26dBm at P1dB. It is a high linearity part with output TOI of 37dBm at 8dBm output per tone.

The TGA2524-SM is available in a low-cost, surface mount 16 lead 3x3 QFN overmold package and is ideally suited for Point-to-Point Radio applications.



### Functional Block Diagram



### Product Features

- Frequency Range: 11.3 – 16 GHz
- Psat: 26.5 dBm
- P1dB: 26 dBm
- Gain: 23 dB, good gain flatness with regulation
- OTOI: 37 dBm at 8 dBm Pout/tone
- NF: 7 dB
- Bias: Vd = 5 V, Idq = 320 mA, Vg = -0.52 V Typical
- Package Dimensions: 3.0 x 3.0 x 0.85 mm

*Performance is typical across frequency.*

*Please reference electrical specification table and data plots for more details.*

### Applications

- Point-to-Point Radio
- Ku-band Sat-Com

### Ordering Information

Part No.	Description
TGA2524-SM	TGA2524-SM, Driver Amplifier
1078986	TGA2524-SM Tape and Reel 7", Qty 1000
TGA2524-SMEVB02	TGA2524-SM Evaluation Board, Qty 1

## Absolute Maximum Ratings

Parameter	Min Value	Max Value	Units
Drain Voltage, $V_d$	-	8	V
Gate Voltage, $V_g$	-2	0	V
Drain to Gate Voltage, $V_d - V_g$	-	12	V
Drain Current, $I_d$	-	450	mA
Gate Current, $I_g$	-8.2	10	mA
Power Dissipation, $P_{diss}$	-	3.6	W
RF Input Power, CW, $T = 25^\circ\text{C}$	-	19	dBm
Channel Temperature, $T_{ch}$	-	200	$^\circ\text{C}$
Mounting Temperature (30 Seconds)	-	260	$^\circ\text{C}$
Storage Temperature	-40	150	$^\circ\text{C}$

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied. Extended application of Absolute Maximum Rating conditions may reduce device reliability.

## Recommended Operating Conditions

Parameter	Value	Units
Drain Voltage	5	V
Drain Current (quiescent, $I_{DQ}$ )	320	mA
Gate Voltage (typical)	-0.52	V
Operating Temperature Range	-40 to 85	$^\circ\text{C}$

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

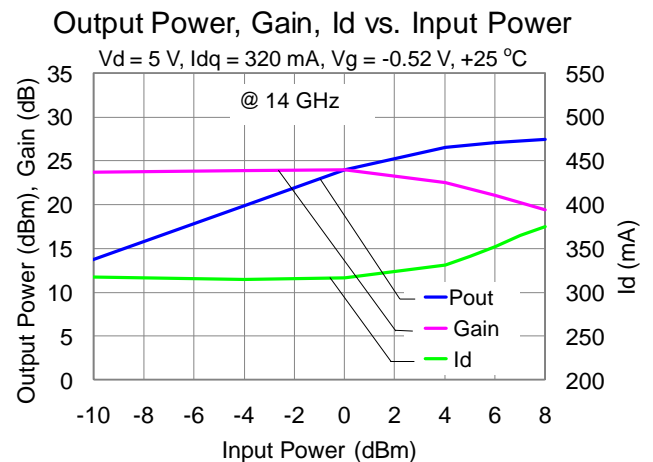
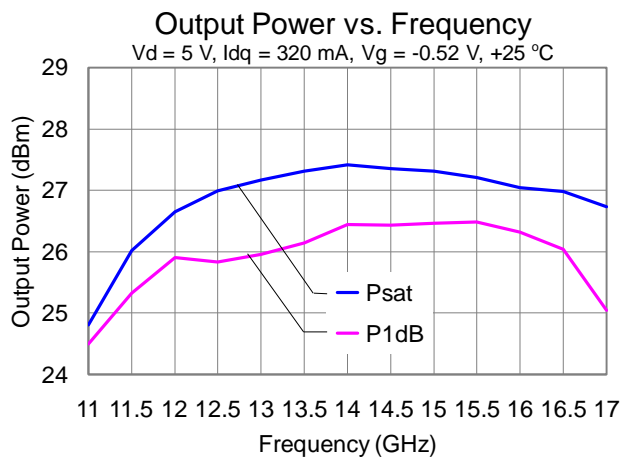
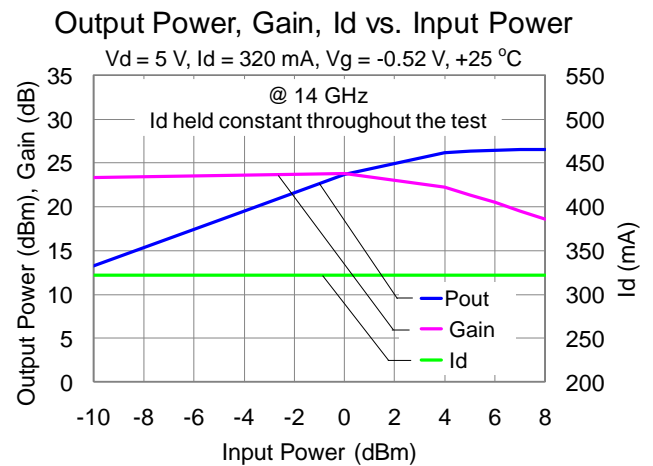
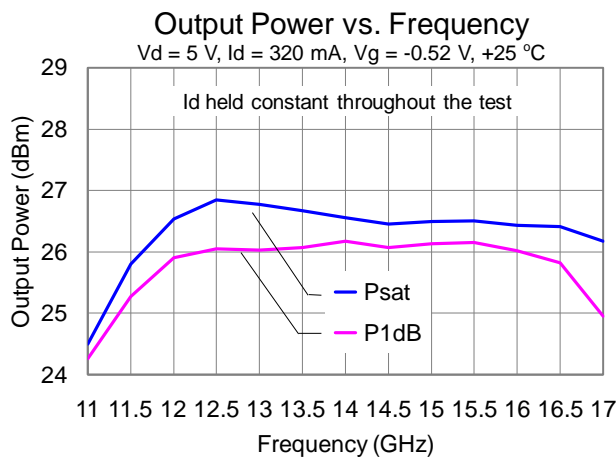
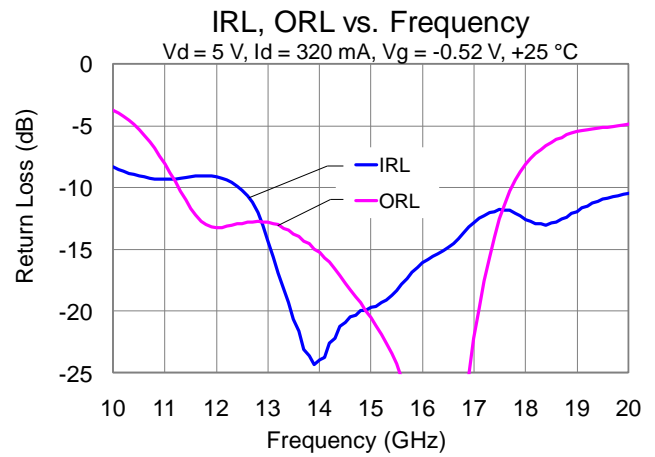
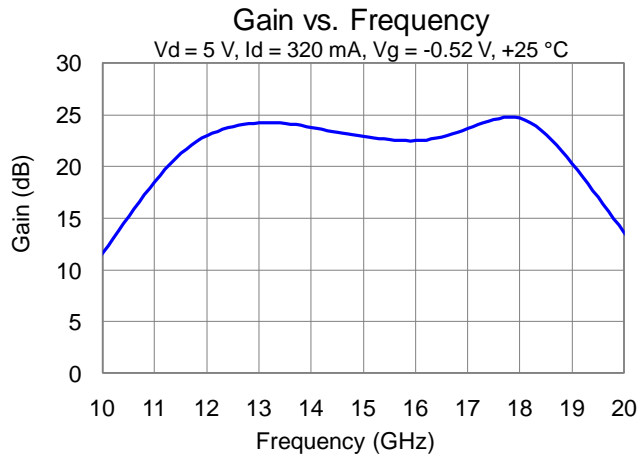
## Electrical Specifications

Test Conditions unless otherwise stated:  $V_D = 5\text{V}$ ,  $I_{DQ} = 320\text{mA}$ ,  $25^\circ\text{C}$ . Data de-embedded to device reference planes

Parameter	Min	Typical	Max	Units
Frequency	11.3		16	GHz
Small Signal Gain (11.3 to 12 GHz)	16	20		dB
Small Signal Gain (12 to 16 GHz)	20	23		dB
Input Return Loss		-12	-8	dB
Output Return Loss		-15	-10	dB
Output Power at Saturation (11.3 to 12 GHz)	24	25		dBm
Output Power at Saturation (12 to 16 GHz)	25.5	26.5		dBm
Output Power at 1dB Compression (11.3 to 12 GHz)	23.5	24.5		dBm
Output Power at 1dB Compression (12 to 16 GHz)	25	26		dBm
Noise Figure		7		dB
Output TOI (@ Drain Current of 300 mA)		37		dBm
Gain Temperature Coefficient		-0.035		dB/ $^\circ\text{C}$
Power Temperature Coefficient		-0.007		dB/ $^\circ\text{C}$

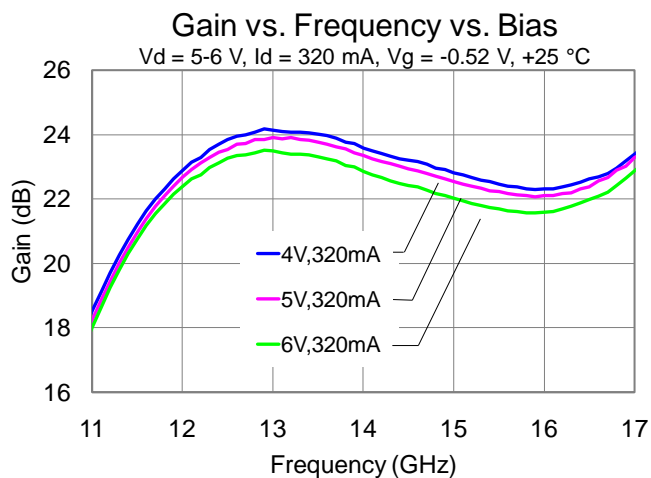
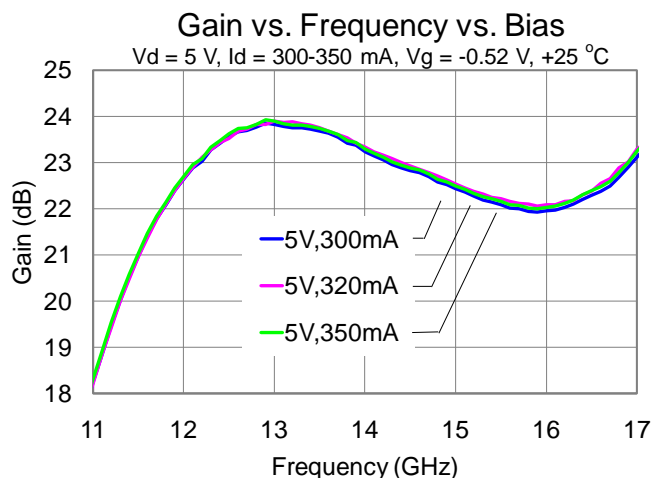
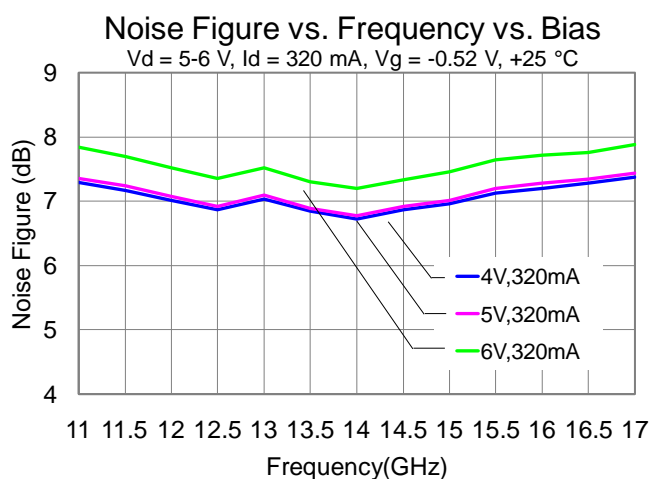
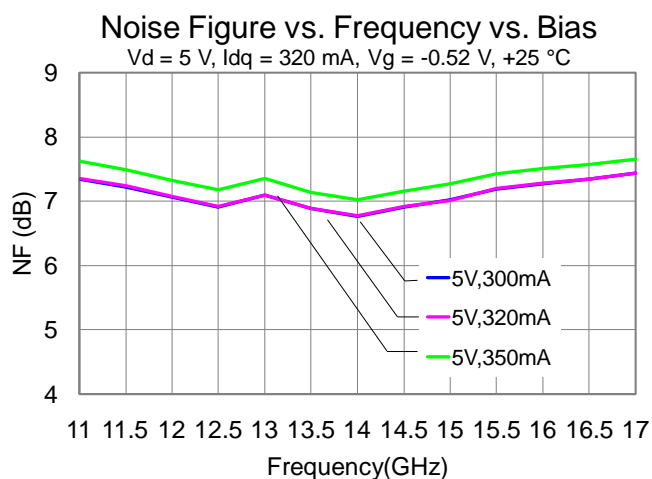
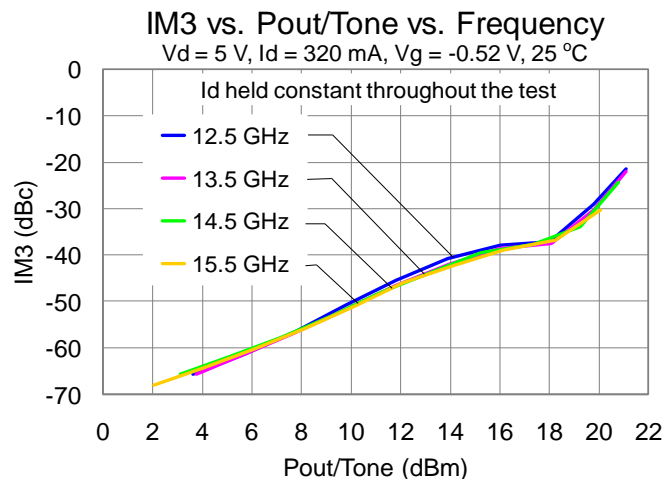
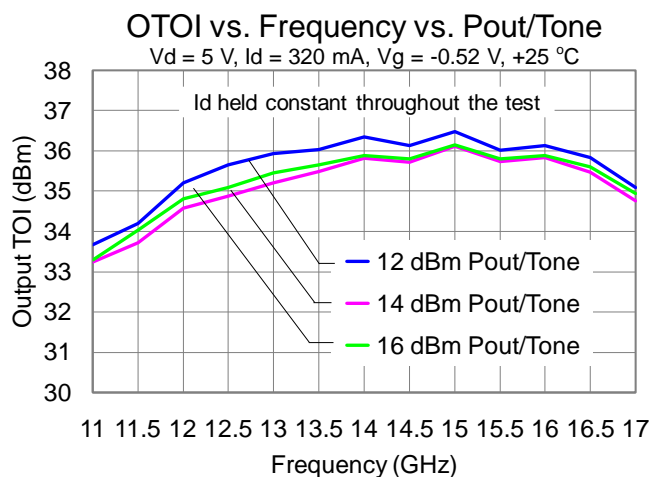
## Performance Plots – Small Signal

Test Conditions unless otherwise stated:  $V_D = 5\text{ V}$ ,  $I_{DQ} = 320\text{ mA}$ ,  $25\text{ }^\circ\text{C}$ .



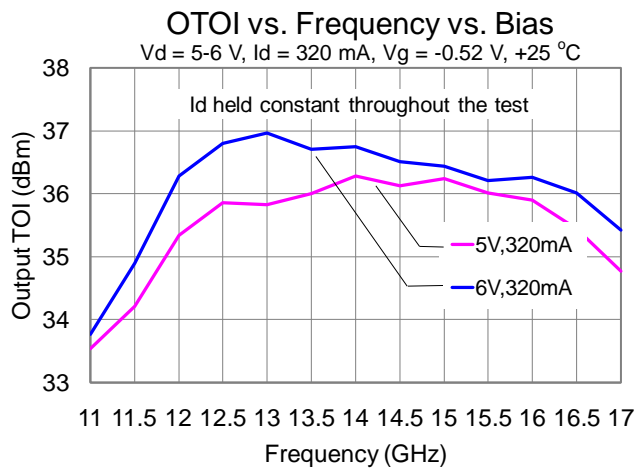
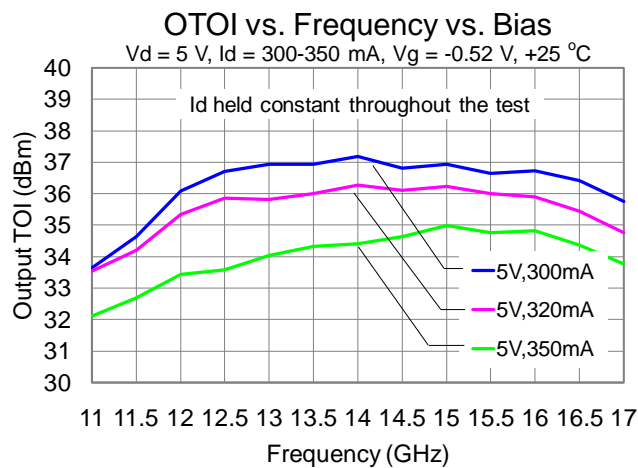
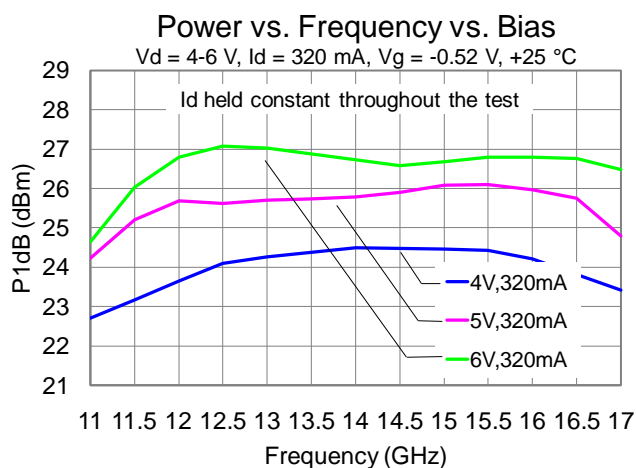
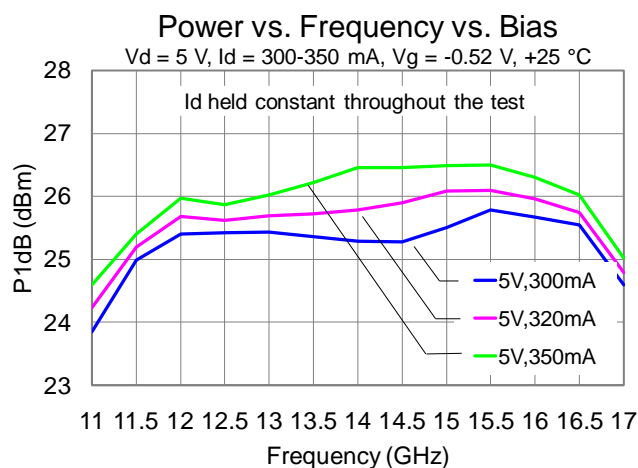
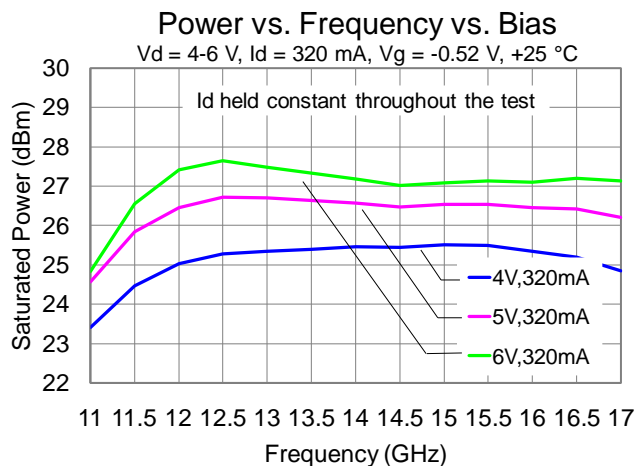
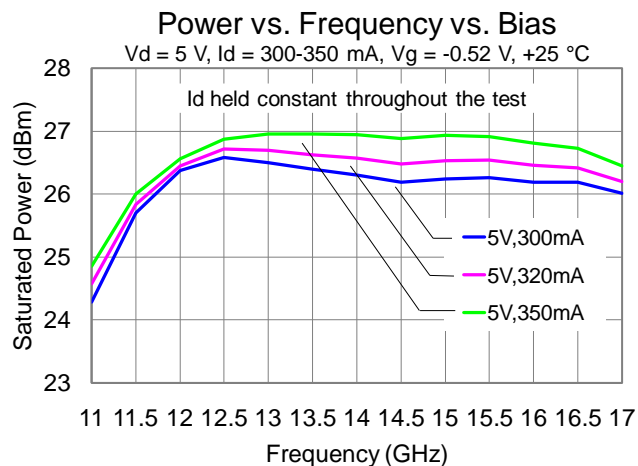
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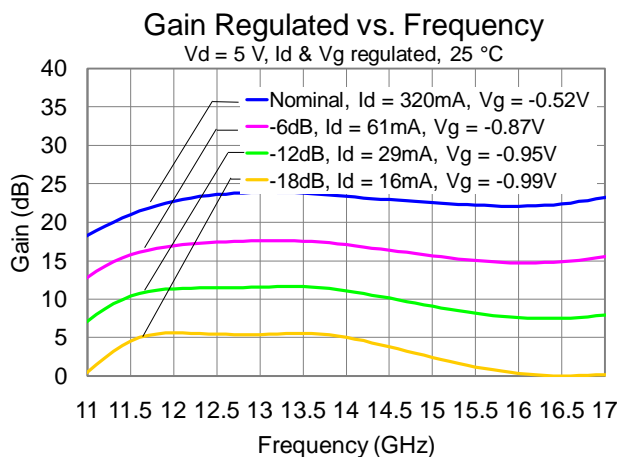
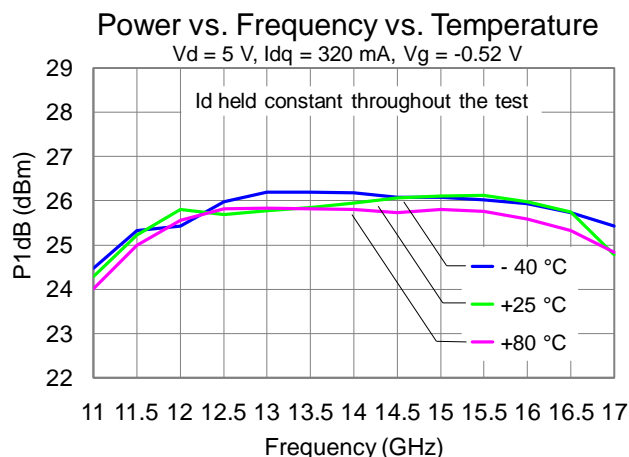
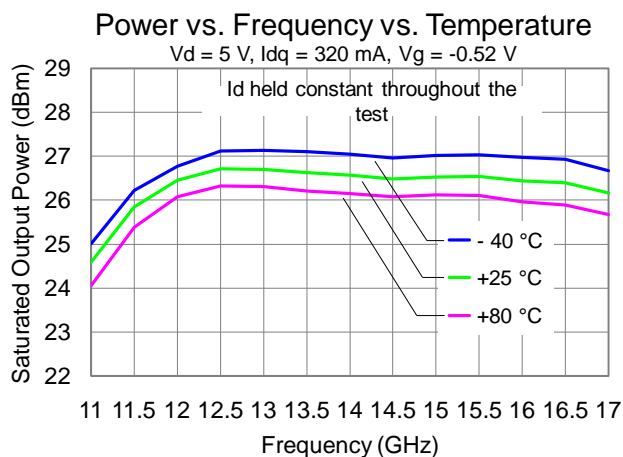
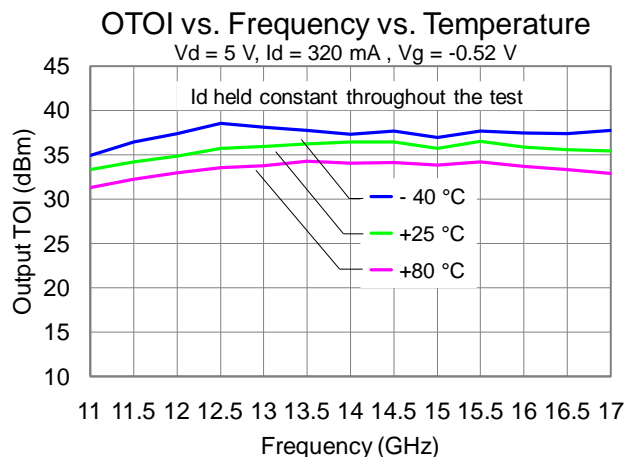
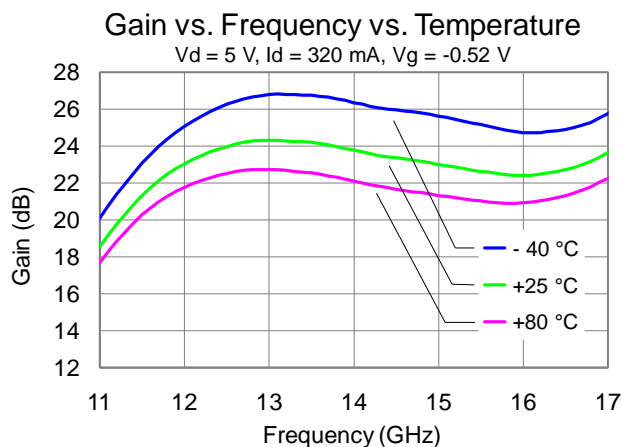
## Performance Plots – Noise Figure

Test Conditions unless otherwise stated:  $V_D = 5\text{ V}$ ,  $I_{DQ} = 320\text{ mA}$ ,  $25\text{ }^\circ\text{C}$ .

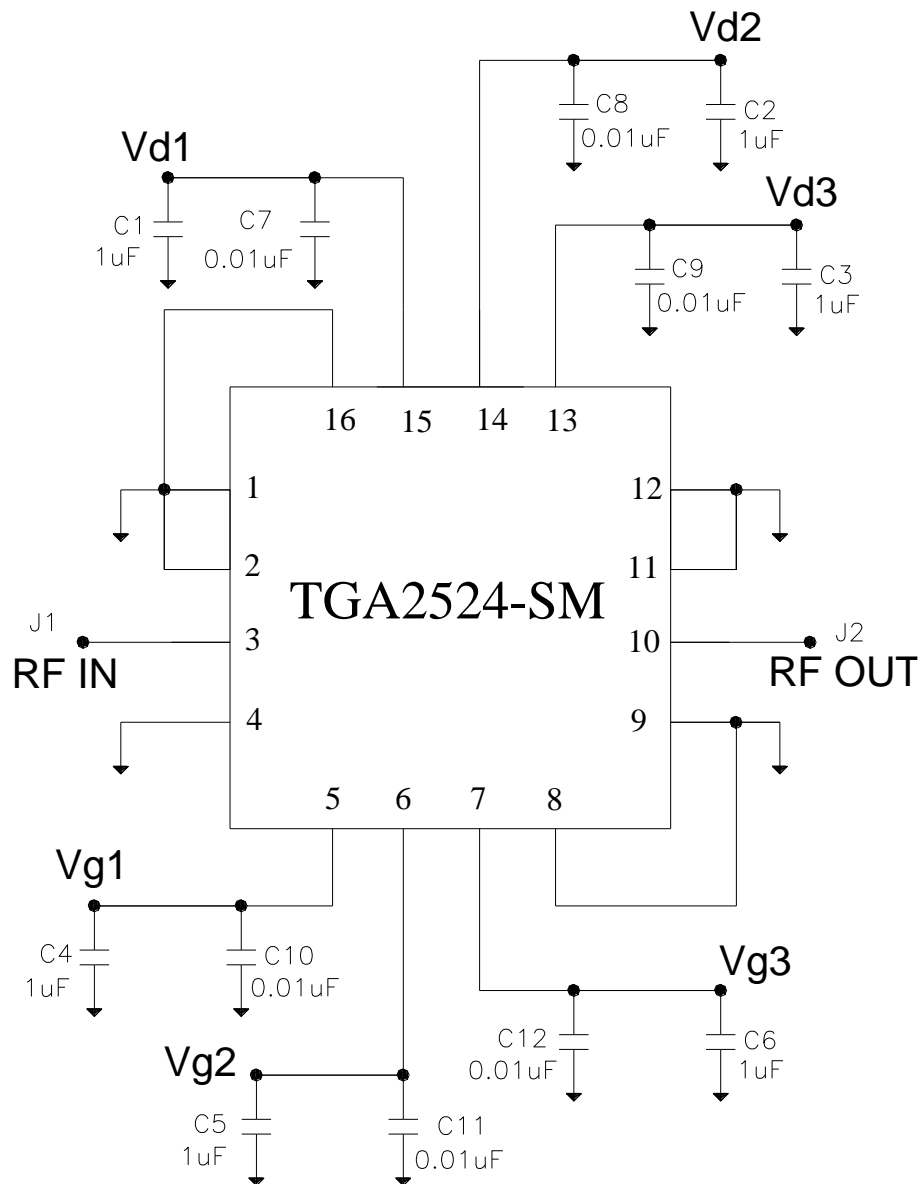


## Performance Plots – Power

Test Conditions unless otherwise stated:  $V_D = 5\text{ V}$ ,  $I_{DQ} = 320\text{ mA}$ ,  $25\text{ }^\circ\text{C}$ .



## Application Circuit



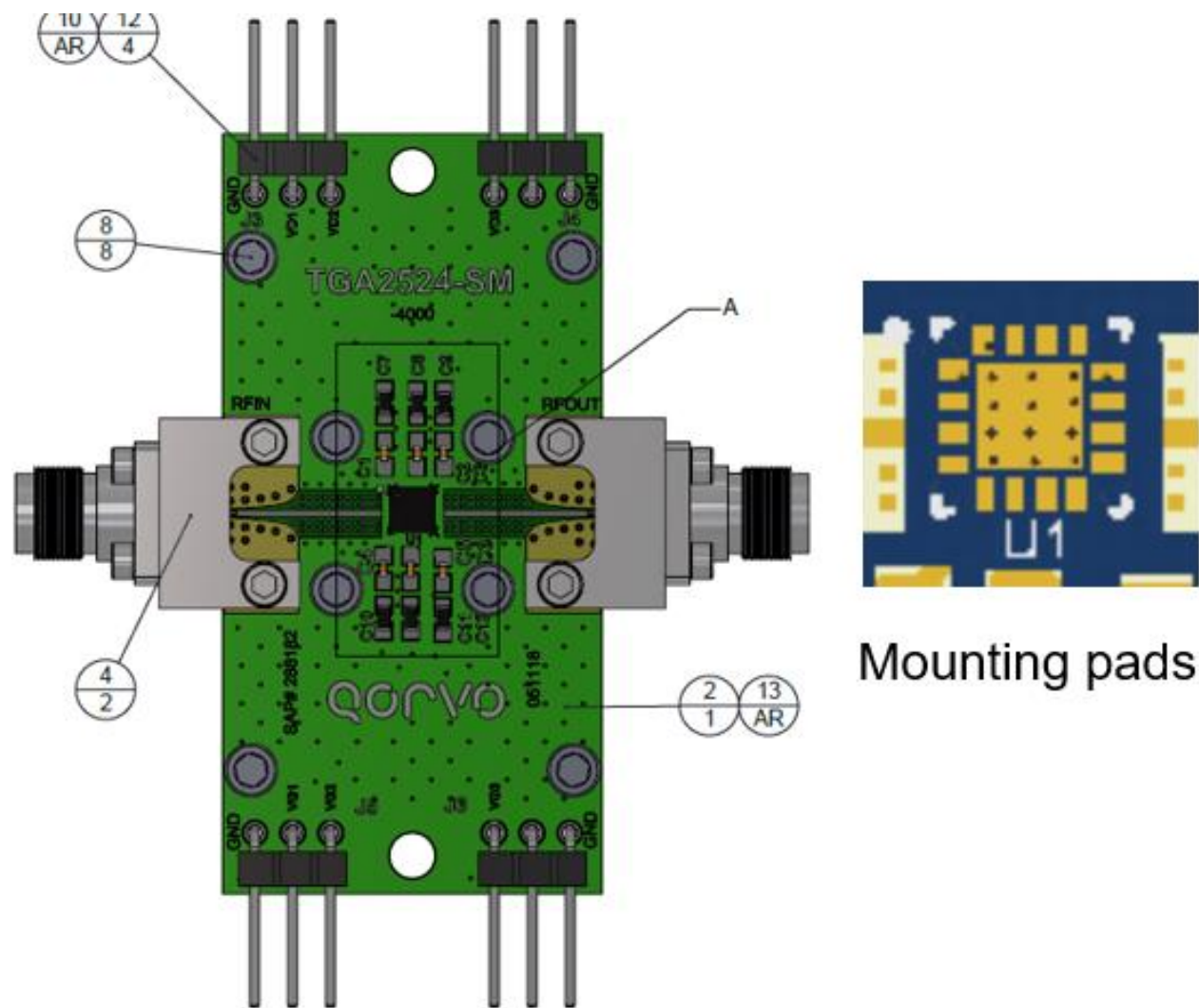
### Bias-up Procedure

1. Vg (externally connect Vg1, Vg2, and Vg3 together) set to -1.5 V
2. Vd (externally connect Vd1, Vd2, and Vd3 together) set to +5 V
3. Adjust Vg more positive until quiescent current is 320 mA, Vg = -0.52 V typical
4. Apply RF signal to RF Input

### Bias-down Procedure

1. Turn off RF signal
2. Reduce Vg to -1.5V. Ensure Id ~ 0 mA
3. Turn Vd to 0 V
4. Turn Vg to 0 V

Evaluation Board and Assembly



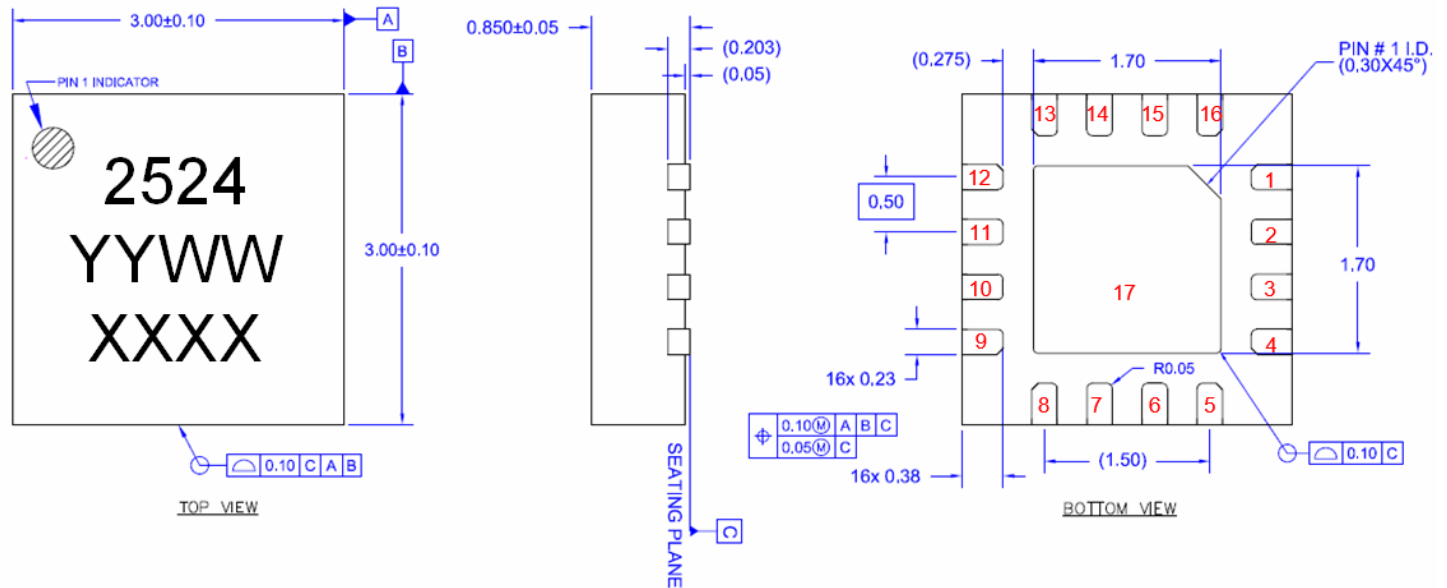
RF Layer is 0.008" thick Rogers Corp. RO4003C ( $\epsilon_r = 3.35$ ). Metal layers are 0.5 oz. copper. The microstrip line at the connector interface is optimized for the Southwest Microwave end launch connector 1092-01A-5.

Bill of Materials

Ref. Des.	Component	Value	Manuf.	Part Number
C1 - C6	Surface Mount	CAP 1.0UF +/-5%, 16V, 1206, COG	AVX	12063C105KAT2A
C7 - C12	Surface Mount	CAP 0.01UF +/-5%, 16V, 0603, COG	AVX	06033C103KAT2A
J1, J2	RF Connector	2.92 MM RF CONNECTOR	Southwest Microwave	1092-01A-5



## Mechanical Drawing & Pad Description



Dimensions in mm.

The package base is copper alloy and the plating material on the leads is matte Sn annealed.

Part Marking: 2524: Part Number, YY = Part Assembly Year, WW = Part Assembly Week, MXXX = Batch ID.

Pin Number	Label	Description
1, 2, 4, 8, 9, 11, 12, 16	N/C	No internal connection. Recommend to GND at the PCB level
3	RF IN	Matched to 50 ohms, DC blocked
5	Vg1	Gate Voltage; bias network is required (V <sub>G</sub> can be tied together at PCB)
6	Vg2	Gate Voltage; bias network is required (V <sub>G</sub> can be tied together at PCB)
7	Vg3	Gate Voltage; bias network is required (V <sub>G</sub> can be tied together at PCB)
10	RF OUT	Matched to 50 ohms, DC blocked
13	Vd3	Drain Voltage; bias network is required (V <sub>D</sub> can be tied together at PCB)
14	Vd2	Drain Voltage; bias network is required (V <sub>D</sub> can be tied together at PCB)
15	Vd1	Drain Voltage; bias network is required (V <sub>D</sub> can be tied together at PCB)
17	GND	Ground Pedestal

## Thermal and Reliability Information

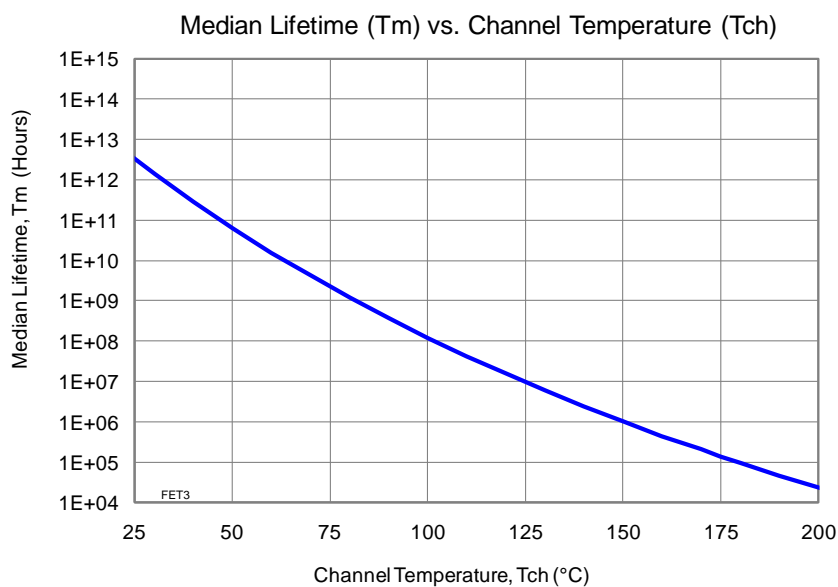
Parameter	Test Conditions	Value	Units
Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>	Tbase = 90 °C	31.1	°C/W
Channel Temperature ( $T_{CH}$ )	Vd = 5 V, Id = 320 mA, Quiescent	140	°C
Median Lifetime ( $T_M$ )	Pdiss = 1.6 W	2.4E06	Hrs
Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>	Tbase = 90 °C	31.1	°C/W
Channel Temperature ( $T_{CH}$ )	Vd = 5 V, Id = 375 mA, RF Pout = 26.5 dBm	134	°C
Median Lifetime ( $T_M$ )	Pdiss = 1.4 W	5.6E06	Hrs

Notes:

1. Thermal resistance is referenced to back of the package.

## Median Lifetime

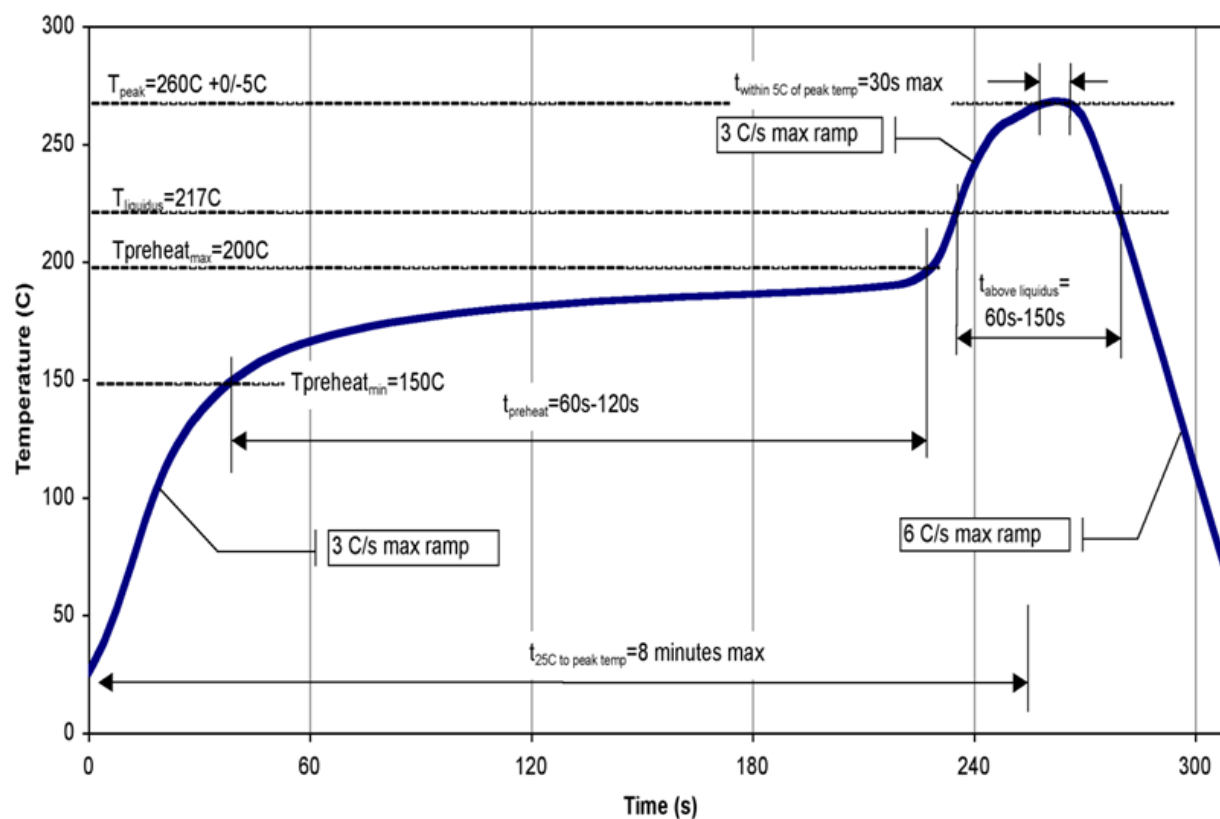
Test Conditions:  $V_D = 4$  V  
Failure Criteria = 10% reduction in  $I_{D\_MAX}$



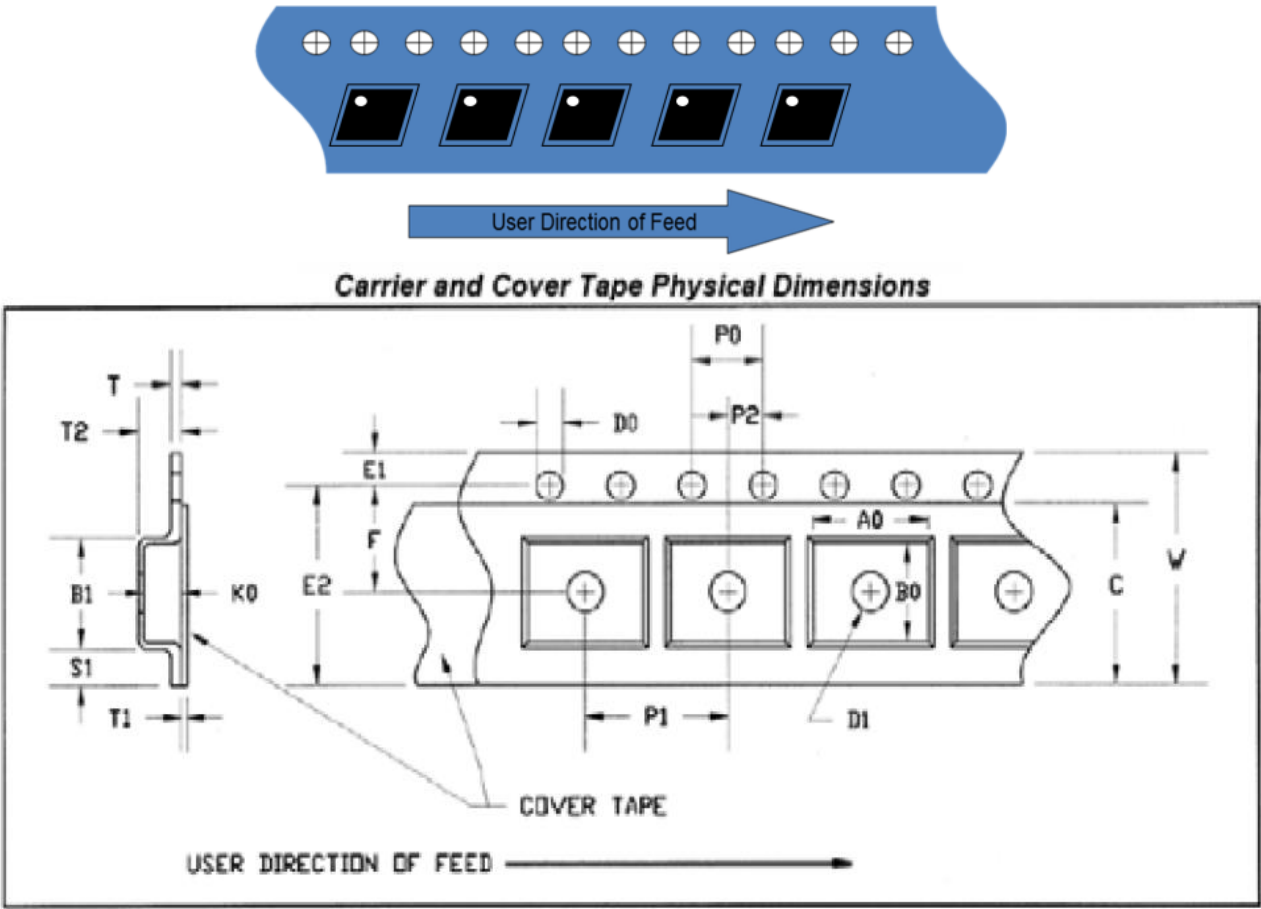
## Solderability

1. Compatible with the latest version of J-STD-020, Lead-free solder (maximum 260 °C reflow temperature) and tin-lead (maximum 245 °C reflow temperature) soldering processes.

## Recommended Soldering Temperature Profile



Tape and Reel Information



CARRIER AND COVER TAPE DIMENSIONS

Part	Feature	Symbol	Size (in)	Size (mm)
Cavity	Length	A0	0.134	3.40
	Width	B0	0.126	3.20
	Depth	K0	0.055	1.40
	Pitch	P1	0.157	4.00
Distance Between Centerline	Cavity to Perforation Length Direction	P2	0.079	2.00
	Cavity to Perforation Width Direction	F	0.138	3.50
Cover Tape	Width	C	0.213	5.40
Carrier Tape	Width	W	0.315	8.00

## Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	1A	ESDA / JEDEC JS-001-2012
ESD – Charged Device Model (CDM)	TBD	ESDA / JEDEC JS-002-2014
MSL – Convection Reflow 260 °C	1	JEDEC standard IPC/JEDEC J-STD-020



Caution!  
ESD-Sensitive Device

## RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>O<sub>2</sub>) Free
- SVHC Free

## Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

**Tel:** 1-844-890-8163

**Web:** [www.qorvo.com](http://www.qorvo.com)

**Email:** [customer.support@qorvo.com](mailto:customer.support@qorvo.com)

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